

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7MET240AFK, TC7MET244AFK

## Octal Bus Buffer

TC7MET240AFK Inverted, 3-State Outputs

TC7MET244AFK Non-Inverted, 3-State Outputs

The TC7MET240AFK and 244AFK are advanced high speed CMOS octal bus buffers fabricated with silicon gate C<sup>2</sup>MOS technology. They achieve the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

The TC7MET240AFK is an inverting 3-state buffer having two active-low output enables. TC7MET244AFK is a non-inverting 3-state buffer, and has two active-low output enables.

These devices are designed to be used with 3-state memory address drivers, etc.

The input voltage are compatible with TTL output voltage.

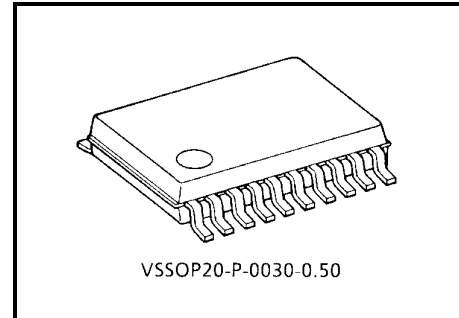
These devices may be used as a level converter for interfacing 3.3 V to 5 V system.

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output <sup>(Note)</sup> pins without regard to the supply voltage. This structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

Note:  $V_{CC} = 0\text{ V}$

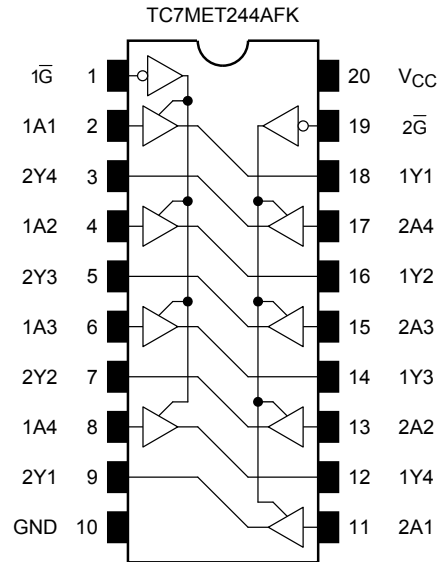
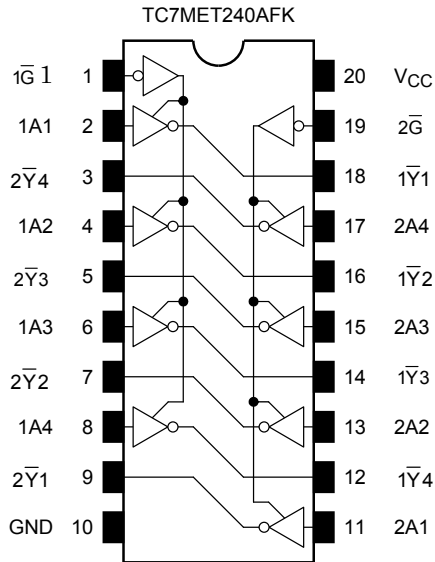
## Features

- High speed:  $t_{pd} = 5.6\text{ ns}$  (typ.) ( $V_{CC} = 5\text{ V}$ )
- Low power dissipation:  $I_{CC} = 4\text{ }\mu\text{A}$  (max) ( $T_a = 25^\circ\text{C}$ )
- Compatible with TTL outputs:  $V_{IL} = 0.8\text{ V}$  (max)  
 $V_{IH} = 2.0\text{ V}$  (min)
- Power down protection is provided on all inputs and outputs.
- Balanced propagation delays:  $t_{pLH} \approx t_{pHL}$
- Low noise:  $V_{OLP} = 1.0\text{ V}$  (max)
- Pin and function compatible with the 74 series (74AC/HC/F/ALS/LS etc.) 240/244 type.

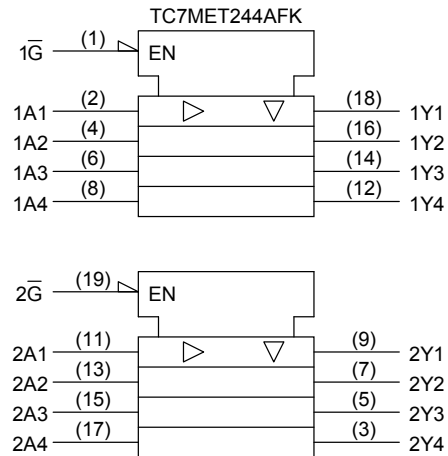
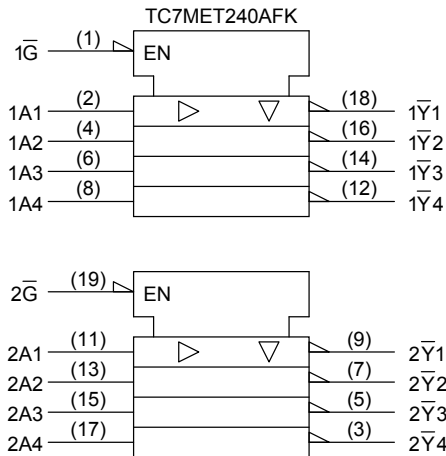


Weight: 0.03 g (typ.)

## Pin Assignment (top view)



## IEC Logic Symbol



## Truth Table

Inputs		Outputs	
$\overline{G}$	$A_n$	$Y_n$	$\overline{Y}_n$
L	L	L	H
L	H	H	L
H	X	Z	Z

X: Don't care

Z: High impedance

$Y_n$ : TC7MET244AFK

$\overline{Y}_n$ : TC7MET240AFK

## Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	$V_{CC}$	-0.5~7.0	V
DC input voltage	$V_{IN}$	-0.5~7.0	V
DC output voltage	$V_{OUT}$	-0.5~7.0 (Note 2)	V
		-0.5~ $V_{CC} + 0.5$ (Note 3)	
Input diode current	$I_{IK}$	-20	mA
Output diode current	$I_{OK}$	±20 (Note 4)	mA
DC output current	$I_{OUT}$	±25	mA
DC $V_{CC}$ /ground current	$I_{CC}$	±75	mA
Power dissipation	$P_D$	180	mW
Storage temperature	$T_{stg}$	-65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in off-state

Note 3: High or low state.  $I_{OUT}$  absolute maximum rating must be observed.

Note 4:  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$

## Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage	$V_{CC}$	4.5~5.5	V
Input voltage	$V_{IN}$	0~5.5	V
Output voltage	$V_{OUT}$	0~5.5 (Note 2)	V
		0~ $V_{CC}$ (Note 3)	
Operating temperature	$T_{opr}$	-40~85	°C
Input rise and fall time	$dt/dv$	0~20	ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

Note 2: Output in off-state

Note 3: High or low state

## Electrical Characteristics

### DC Characteristics

Characteristics		Symbol	Test Condition	Ta = 25°C			Ta = -40~85°C		Unit		
				V <sub>CC</sub> (V)	Min	Typ.	Max	Min		Max	
Input voltage	High level	V <sub>IH</sub>	—	4.5~5.5	2.0	—	—	2.0	—	V	
	Low level	V <sub>IL</sub>	—	4.5~5.5	—	—	0.8	—	0.8		
Output voltage	High level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	4.5	4.4	4.5	—	4.4	—	V
				I <sub>OH</sub> = -8 mA	4.5	3.94	—	—	3.80	—	
	Low level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	4.5	—	0	0.1	—	0.1	
				I <sub>OL</sub> = 8 mA	4.5	—	—	0.36	—	0.44	
3-state output off-state current		I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND	5.5	—	—	±0.25	—	±2.50	μA	
Input leakage current		I <sub>N</sub>	V <sub>IN</sub> = 5.5 V or GND	0~5.5	—	—	±0.1	—	±1.0	μA	
Quiescent supply current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	—	—	4.0	—	40.0	μA	
		I <sub>CC(T)</sub>	Per input: V <sub>IN</sub> = 3.4 V Other input: V <sub>CC</sub> or GND	5.5	—	—	1.35	—	1.50	mA	
Output leakage current		I <sub>OPD</sub>	V <sub>OUT</sub> = 5.5 V	0	—	—	0.5	—	5.0	μA	

### AC Characteristics (Input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)

Characteristics		Symbol	Test Condition	Ta = 25°C			Ta = -40~85°C		Unit	
				V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Typ.	Max		Min
Propagation delay time (TC7MET240AFK)	t <sub>pLH</sub> t <sub>pHL</sub>	—	5.0 ± 0.5	15	—	5.6	7.8	1.0	9.0	ns
				50	—	6.1	8.8	1.0	10.0	
Propagation delay time (TC7MET244AFK)	t <sub>pLH</sub> t <sub>pHL</sub>	—	5.0 ± 0.5	15	—	5.4	7.4	1.0	8.5	ns
				50	—	5.9	8.4	1.0	9.5	
3-state output enable time	t <sub>pZL</sub> t <sub>pZH</sub>	R <sub>L</sub> = 1 kΩ	5.0 ± 0.5	15	—	7.7	10.4	1.0	12.0	ns
				50	—	8.2	11.4	1.0	13.0	
3-state output disable time	t <sub>pLZ</sub> t <sub>pHZ</sub>	R <sub>L</sub> = 1 kΩ	5.0 ± 0.5	50	—	8.8	11.4	1.0	13.0	ns
Output to output skew	t <sub>osLH</sub> t <sub>osHL</sub>	(Note 1)	5.0 ± 0.5	50	—	—	1.0	—	1.0	ns
Input capacitance	C <sub>IN</sub>	—	—	—	—	4	10	—	10	pF
Output capacitance	C <sub>OUT</sub>	—	—	—	—	9	—	—	—	pF
Power dissipation capacitance (Note 2)	C <sub>PD</sub>	TC7MET240AFK	—	—	—	19	—	—	—	pF
		TC7MET244AFK	—	—	—	18	—	—	—	

Note 1: Parameter guaranteed by design.

$$t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|$$

Note 2: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$$

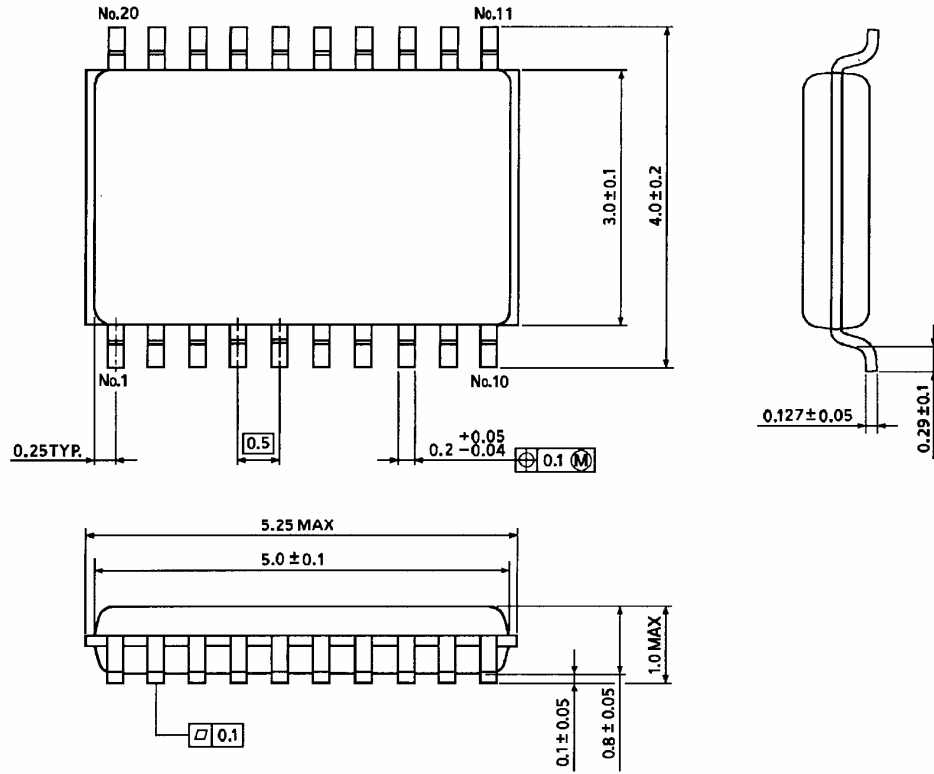
**Noise Characteristics (Input:  $t_r = t_f = 3 \text{ ns}$ )**

Characteristics	Symbol	Test Condition	Ta = 25°C			Unit
			V <sub>CC</sub> (V)	Typ.	Limit	
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	C <sub>L</sub> = 50 pF	5.0	0.8	1.0	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	C <sub>L</sub> = 50 pF	5.0	-0.8	-1.0	V
Minimum high level dynamic input voltage V <sub>IH</sub>	V <sub>IHD</sub>	C <sub>L</sub> = 50 pF	5.0	—	2.0	V
Maximum high level dynamic input voltage V <sub>IL</sub>	V <sub>ILD</sub>	C <sub>L</sub> = 50 pF	5.0	—	0.8	V

**Package Dimensions**

VSSOP20-P-0030-0.50

Unit : mm



Weight: 0.03 g (typ.)

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20070701-EN GENERAL

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